

2N5246

N-Channel RF Amplifier

- This device is designed for HF/VHF mixer/amplifier and applications where process 50is not adequate. Sufficient gain and low noise for sensitive receivers.
- Sourced from process 90.



Absolute Maximum Ratings* T_a=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DG}	Drain-Gate Voltage	30	V
V_{GS}	Gate-Source Voltage	-30	V
I_{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

^{*} This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units	
Off Charac	Off Characteristics					
V _{(BR)GSS}	Gate-Source Breakdwon Voltage	$I_G = 1.0 \mu A, V_{DS} = 0$	-30		V	
I _{GSS}	Gate Reverse Current	$V_{GS} = 25V, V_{DS} = 0$		-1.0	nA	
V _{GS(off)}	Gate-Source Cutoff Voltage	$V_{DS} = 15V, I_{D} = 1.0nA$	-0.5	-4.0	V	
On Characteristics						
I _{DSS}	Zero-Gate Voltage Drain Current *	V _{DS} = 15V, V _{GS} = 0	1.5	7.0	mA	
Small Signal Characteristics						
gfs	Forward Transferconductance	$V_{GS} = 0V, V_{DS} = 15V, f = 1.0kHz$	3000	9500	μmhos	
goss	Common- Source Output Conductance	$V_{GS} = 0V, V_{DS} = 15V, f = 1.0kHz$		50	μmhos	

^{*} Pulse Test: Pulse ≤ 300μs

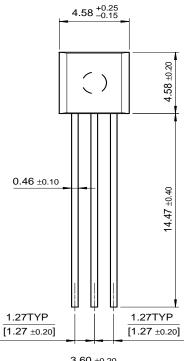
Thermal Characteristics T_A=25°C unless otherwise noted

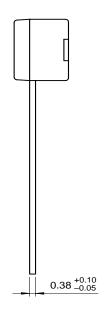
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

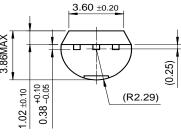
These rating are based on a maximum junction temperature of 150 degrees C.
 These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Package Dimensions

TO-92







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PRODUCT STATUS DEFINITIONS

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